

SPECIFICATION OF LED CHIP

C570-25V

[Yellow Green]

1) Commodity Type and Physical Characteristics.

- | | | | |
|----------------------|--------------|------------------|-------------------------|
| 1. Material | InGaAlP/GaAs | | |
| 2. Electrode | Top Side | P (anode) side | : Au Alloy/Au or Au Pad |
| | Bottom Side | N (cathode) side | : Au Alloy |
| 3. Electrode Pattern | Fig.1 | | |
| 4. Chip Size | Fig.2 | | |
| 5. Chip Thickness | Fig.2 | | |
| 6. Emission Area | Fig.2 | | |

2) Electro-Optical Characteristics [Ta=25°C]

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	V _f	I _f =20mA		2.2	2.5	V
Reverse Current	I _r	V _r =5V			10	uA
Brightness	I _v	I _f =20mA	20	35		mcd
Power Intensity	P _o	I _f =20mA	0.15	0.25		mW
Peak Wavelength	λ _p	I _f =20mA	565	570	575	nm
Spectral Radiation Bandwidth	Δλ	I _f =20mA		20		nm

‡ Die shall be mounted on TO=18 gold header without resin coated.

[Unit: um]

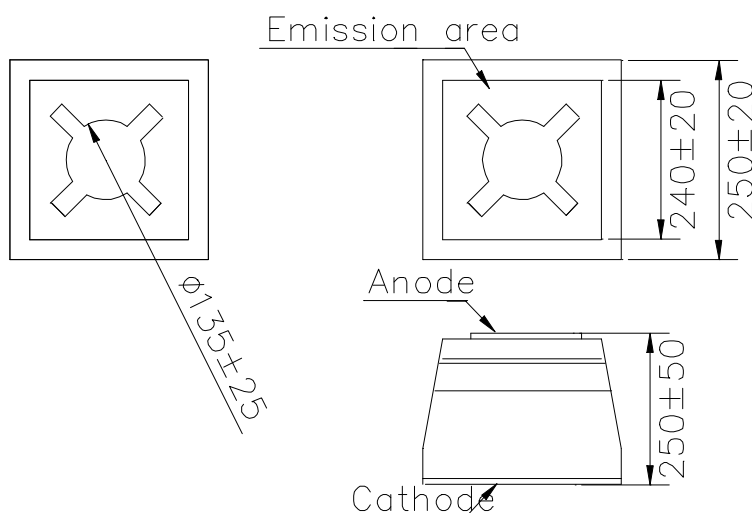


Fig.1 Electrode Pattern

Fig.2 Chip size and Emission Area